Diode Semiconductor Device - Page 1 of 1



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	Material:
Glass	
Overall Le	-
0.300 inche	
Terminal L	ength:
1.000 inche	25
Overall Dia	ameter:
0.140 inche	25
Joint Elect	ronic Device Engineering Council/jedec/case Outline Designation:
Do-15	
Mounting	Method:
Terminal	
Features P	Provided:
Hermeticall	y sealed case
Semicond	uctor Material:
Silicon	
Voltage Ra	ating In Volts Per Characteristic:
37.0 revers	se voltage, dc
Current Ra	ating Per Characteristic:
0.10 millian	nperes forward current, average peak
Power Rat	ing Per Characteristic:
1.0 watts si	mall-signal input power, common-collector preset
Maximum	Operating Tempurature Per Measurement Point:
175.0 degre	ees celsius ambient air
Terminal T	ype And Quantity:
2 uninsulate	ed wire lead
Shelf Life:	
N/a	
Unit Of Me	asure:
Demilitariz	ation:
No	
Fiig:	
A110a0	